U.S. Department of Commerce, Patent and Trademark	Atty. Docket No.	Application No.
INFORMATION DISCLOSURE STATEMENT BY APPLICANT	SNDK.268US2	10/678,918
	Applicant(s)	Conf. No.
(Use several sheets if necessary)	Raul-Adrian Cernea and Yan Li	1420
	Filing Date	Group
	October 2, 2003	2827

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*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
DL	1	4,785,427	Nov. 15, 1988	Young			
	2	5,093,806	Mar. 3, 1992	Tran			
	3	5,245,571	Sep. 14, 1993	Takahashi			
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Foreign Patent Documents

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DL	11	1134746 A2	Sep. 19, 2001	Europe				
DL	12	WO 02/069340	Sep. 6, 2002	WIPO				

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

DL	13	International Search Report corresponding to PCT/US03/30133, International Searching Authority, European Patent Office, mailed February 16, 2004, (filed September 18, 2003), 4 pages.
DL	14	Eitan et al., "NROM: A Novel Localized Trapping 2-Bit Nonvolatile Memory Cell," IEEE Electron Device Letters, vol. 21, no. 11, Nov. 2000, pp. 543-545.

Examiner	Date Considered 1/06

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.